



# SPP9435A

## P-Channel Enhancement Mode MOSFET

### DESCRIPTION

The SPP9435A is the P-Channel logic enhancement mode power field effect transistors are produced using high cell density , DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application , notebook computer power management and other battery powered circuits where high-side switching .

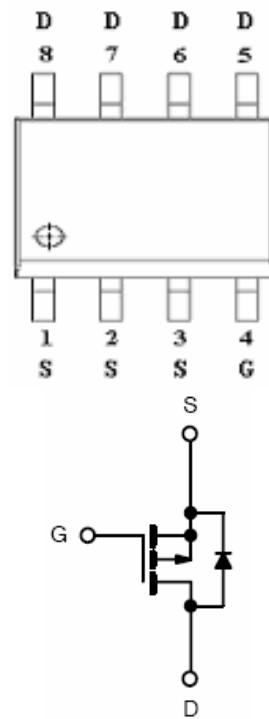
### FEATURES

- ◆ -30V/-5.3A,R<sub>DS(ON)</sub>= 65mΩ@V<sub>GS</sub>=- 10V
- ◆ -30V/-4.2A,R<sub>DS(ON)</sub>= 100mΩ@V<sub>GS</sub>=-4.5V
- ◆ Super high density cell design for extremely low RDS (ON)
- ◆ Exceptional on-resistance and maximum DC current capability
- ◆ SOP – 8P package design

### APPLICATIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

### PIN CONFIGURATION(SOP – 8P)



### PART MARKING



A : Lot Code  
B : Date Code



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### PIN DESCRIPTION

Pin	Symbol	Description
1	S	Source
2	S	Source
3	S	Source
4	G	Gate
5	D	Drain
6	D	Drain
7	D	Drain
8	D	Drain

### ORDERING INFORMATION

Part Number	Package	Part Marking
SPP9435AS8RG	SOP- 8P	SPP9435A
SPP9435AS8TG	SOP- 8P	SPP9435A

※ SPP9435AS8RG : 13" Tape Reel ; Pb – Free

※ SPP9435AS8TG : Tube ; Pb – Free

### ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter	Symbol	Typical	Unit
Drain-Source Voltage	V <sub>DSS</sub>	-30	V
Gate –Source Voltage	V <sub>GSS</sub>	±20	V
Continuous Drain Current(T <sub>J</sub> =150°C)	T <sub>A</sub> =25°C	-6.8	A
	T <sub>A</sub> =70°C		
Pulsed Drain Current	I <sub>DM</sub>	-30	A
Continuous Source Current(Diode Conduction)	I <sub>S</sub>	-2.3	A
Power Dissipation	T <sub>A</sub> =25°C	2.8	W
	T <sub>A</sub> =70°C		
Operating Junction Temperature	T <sub>J</sub>	-55/150	°C
Storage Temperature Range	T <sub>STG</sub>	-55/150	°C
Thermal Resistance-Junction to Ambient	R <sub>θJA</sub>	70	°C/W



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### ELECTRICAL CHARACTERISTICS

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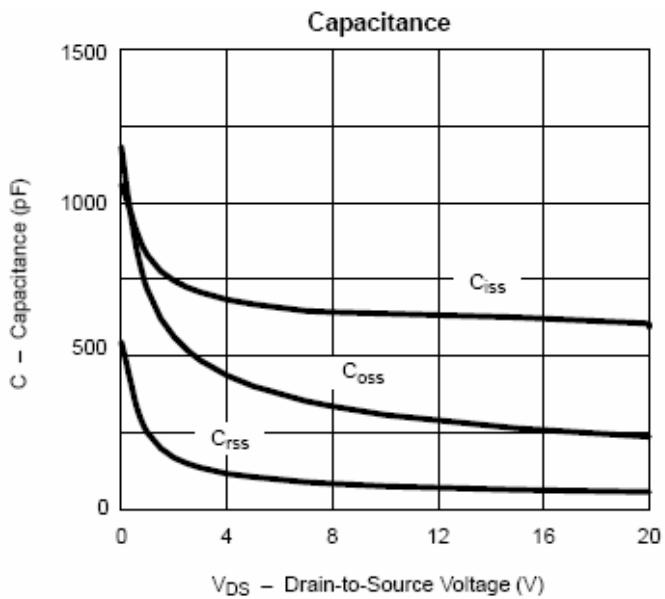
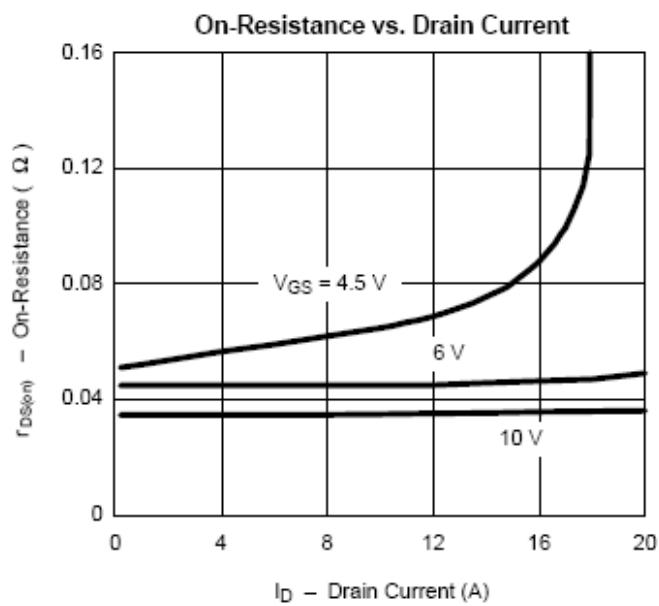
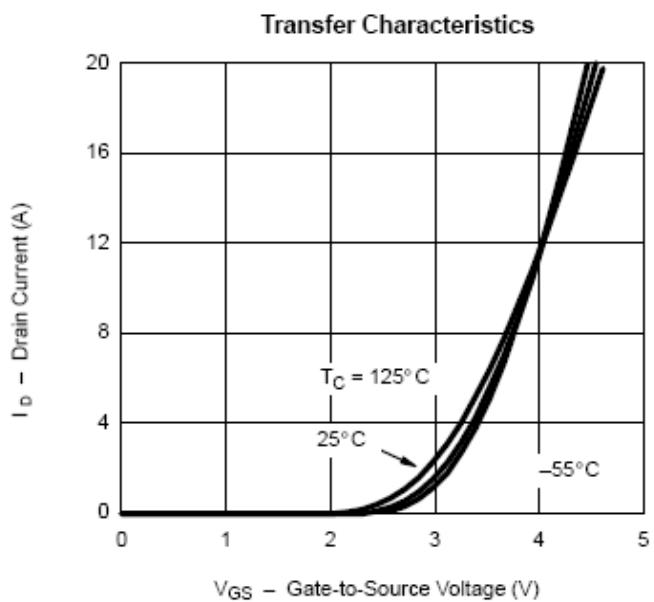
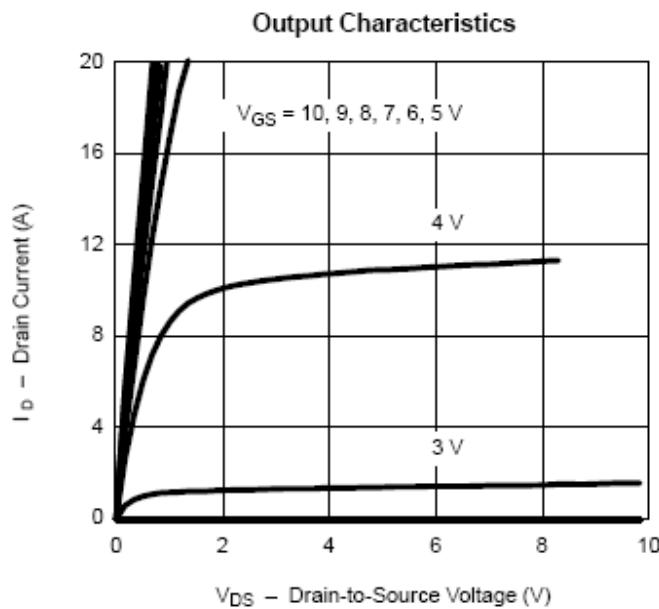
Parameter	Symbol	Conditions	Min.	Typ	Max.	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V, ID=-250uA	-30			V
Gate Threshold Voltage	VGS(th)	VDS=VGS, ID=-250uA	-1.0		-3.0	
Gate Leakage Current	IGSS	VDS=0V, VGS=±20V			±100	nA
Zero Gate Voltage Drain Current	IDSS	VDS=-24V, VGS=0V			-1	uA
		VDS=-24V, VGS=0V TJ=85°C			-5	
On-State Drain Current	ID(on)	VDS= -5V, VGS =-4.5V	-10			A
Drain-Source On-Resistance	RDS(on)	VGS=-10V, ID=-5.3A		0.055	0.065	Ω
		VGS=-4.5V, ID=-4.2A		0.090	0.100	
Forward Transconductance	gfs	VDS=-15V, ID=-5.7A		13		S
Diode Forward Voltage	VSD	IS= -2.0A, VGS =0V		-0.8	-1.2	V
<b>Dynamic</b>						
Total Gate Charge	Qg	VDS=-15V, VGS=-10V ID= -5.3A		10	15	nC
Gate-Source Charge	Qgs			3.4		
Gate-Drain Charge	Qgd			1.7		
Input Capacitance	Ciss	VDS=-15V, VGS=0V f=1MHz		560		pF
Output Capacitance	Coss			100		
Reverse Transfer Capacitance	Crss			67		
Turn-On Time	td(on)	VDD=-15V, RL=15Ω ID= -1.0A, VGEN=-10V RG=6Ω		7	15	nS
	tr			10	20	
Turn-Off Time	td(off)			40	80	
	tf			20	40	



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### TYPICAL CHARACTERISTICS

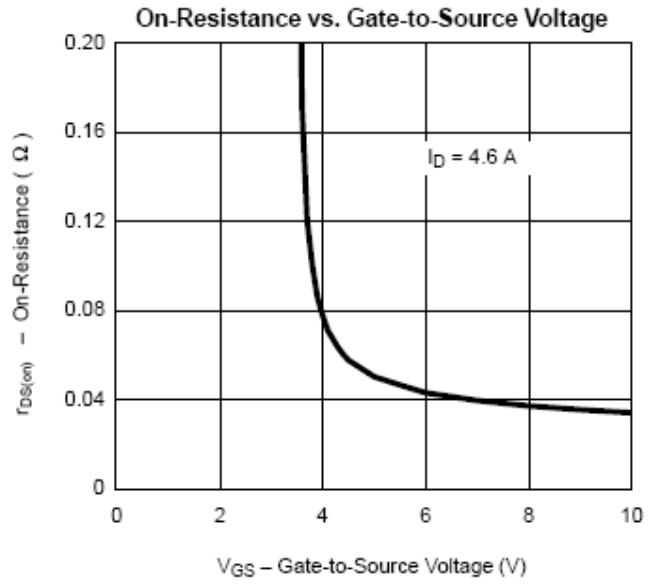
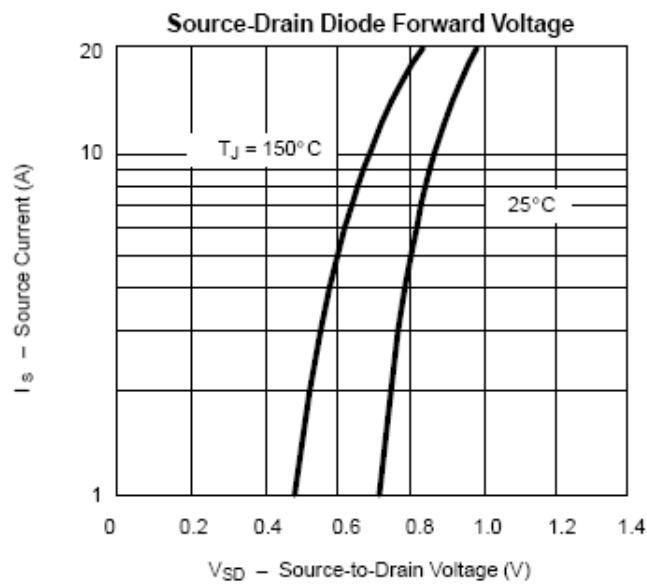
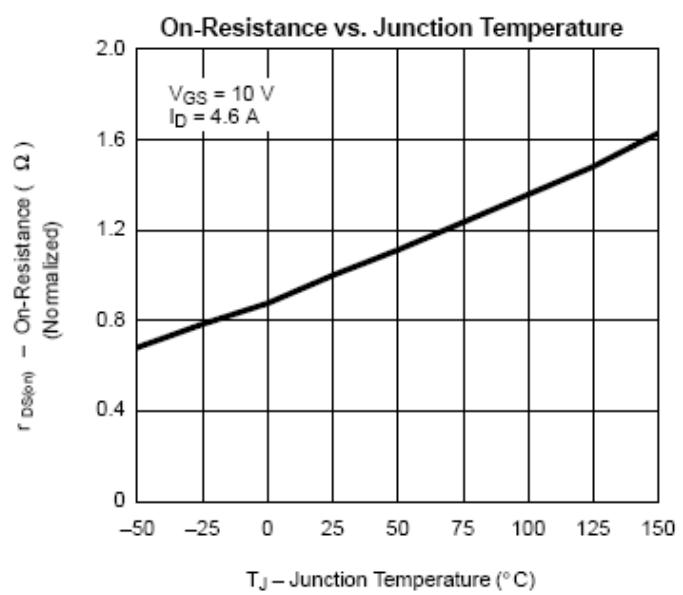
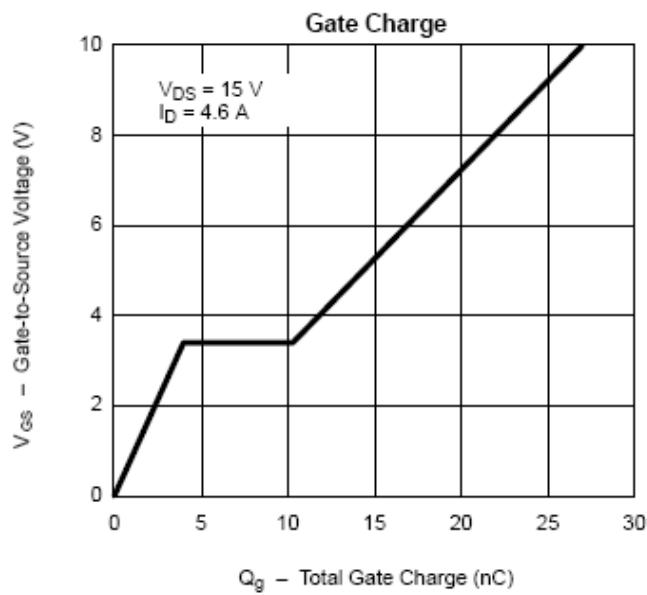




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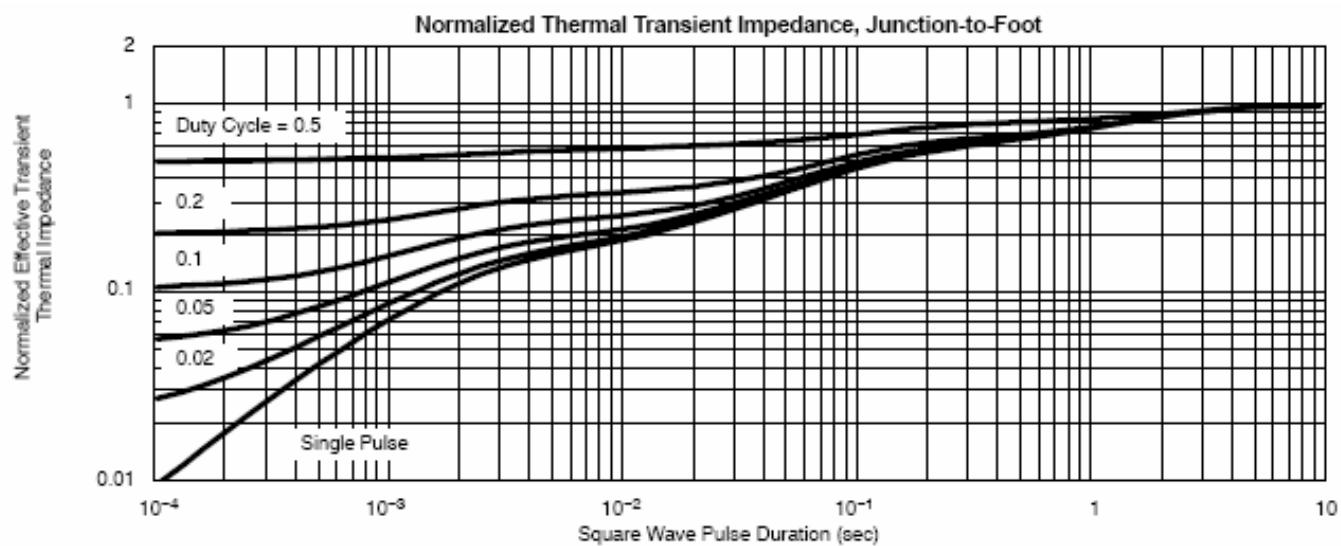
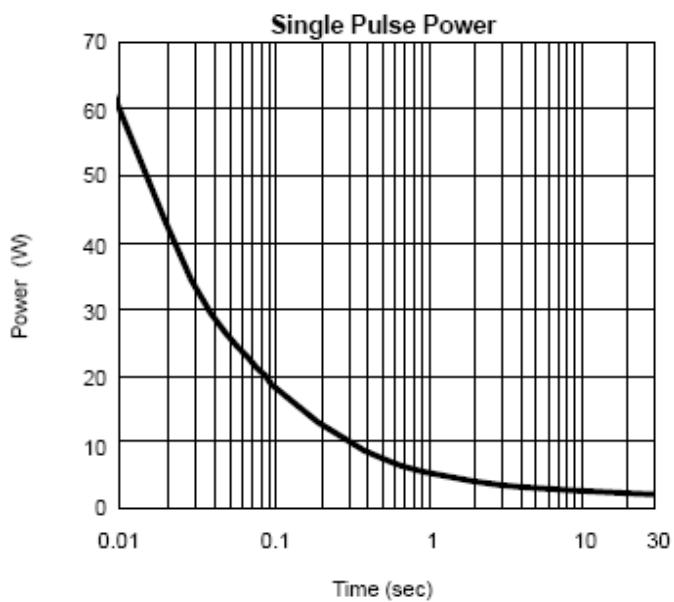
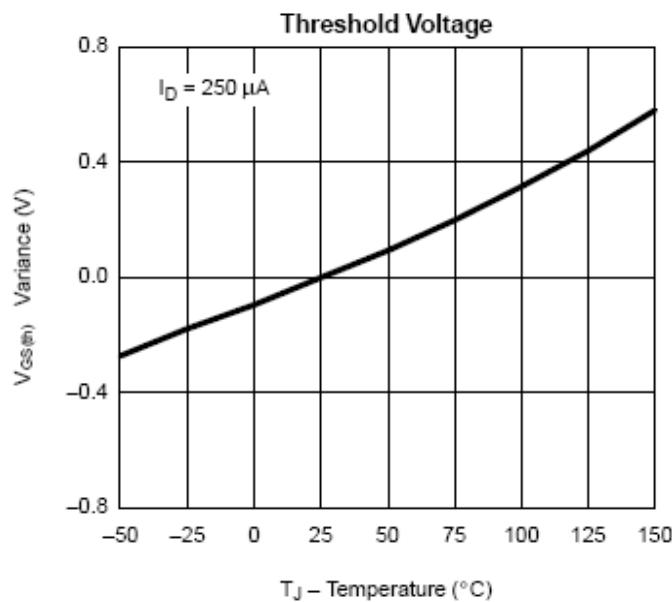




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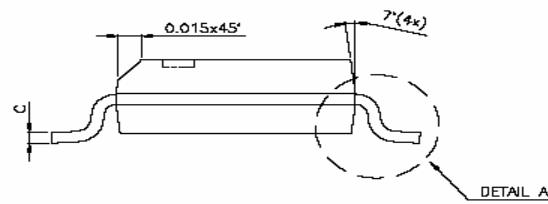
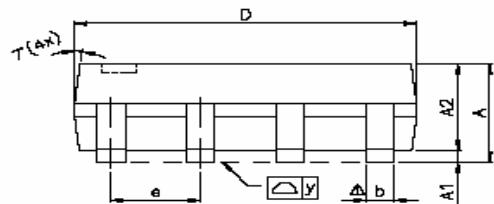
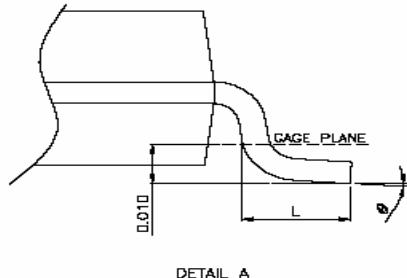
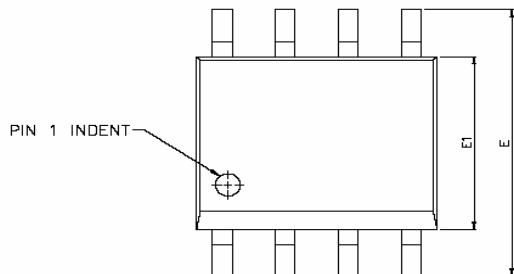




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### SOP- 8 PACKAGE OUTLINE



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.47	1.60	1.73	0.058	0.063	0.068
A1	0.10	—	0.25	0.004	—	0.010
A2	—	1.45	—	—	0.057	—
b	0.33	0.41	0.51	0.013	0.016	0.020
C	0.19	0.20	0.25	0.0075	0.008	0.0098
D	4.80	4.85	4.95	0.189	0.191	0.195
E	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
e	—	1.27	—	—	0.050	—
L	0.38	0.71	1.27	0.015	0.028	0.050
$\triangle_y$	—	—	0.076	—	—	0.003
$\theta$	0°	—	8°	0°	—	8°